


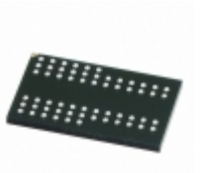

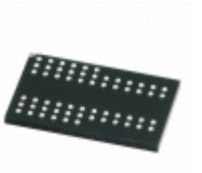
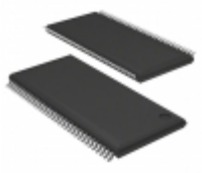


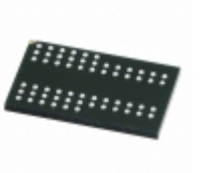
	<h2 style="color: red;">IS43R16320D-6BI</h2>	
	Hersteller-Teilenummer:	IS43R16320D-6BI
	Hersteller / Marke:	ISSI (Integrated Silicon Solution, Inc.)
	Teil der Beschreibung:	IC DRAM 512M PARALLEL 60TFBGA
Datenblätter:	 IS43R16320D-6BI.pdf	
RoHs Status:	Bleifrei / RoHS-konform	
Lagerzustand:	New original, 2500 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	IS43R16320D-6BI
Hersteller	ISSI (Integrated Silicon Solution, Inc.)
Beschreibung	IC DRAM 512M PARALLEL 60TFBGA
Kategorie	Integrierte Schaltungen (ICs) > Erinnerung
Teilstatus	2500 pcs Stock
detaillierte Beschreibung	SDRAM - DDR Memory IC 512M (32M x 16) Parallel
Serie	-
Technologie	SDRAM - DDR
Betriebstemperatur	-40°C ~ 85°C (TA)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	60-TFBGA
Supplier Device-Gehäuse	60-TFBGA (13x8)
Spannungsversorgung	2.3 V ~ 2.7 V
Speichertyp	Volatile
Speichergröße	512M (32M x 16)
Uhrfrequenz	166MHz
Zugriffszeit	700ps
Speicherformat	DRAM
Schreibzyklus Zeit - Wort, Seite	15ns
Speicherschnittstelle	Parallel
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	3 (168 Hours)

IS43R16320D-6BI ist neu im Original, Suche IS43R16320D-6BI Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IS43R16320D-6BI ISSI (Integrated Silicon Solution, Inc.) mit Garantie und Vertrauen. Anfrage IS43R16320D-6BI: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>IS43R16320D-5TLI ISSI (Integrated Silicon Solution, Inc.) IC SDRAM 512MBIT 200MHZ 66TSOP</p>	 <p>IS43R16320D-6BL ISSI (Integrated Silicon Solution, Inc.) IC SDRAM 512MBIT 167MHZ 60BGA</p>	 <p>IS43R16320D-6BI-TR ISSI ISSI BGA</p>	 <p>IS43R16320D-6BL-TR ISSI (Integrated Silicon Solution, Inc.) IC SDRAM 512MBIT 167MHZ 60BGA</p>
 <p>IS43R16320D-5TL ISSI (Integrated Silicon Solution, Inc.) IC SDRAM 512MBIT 200MHZ 66TSOP</p>	 <p>IS43R16320D-6BI ISSI ISSI FBGA60</p>	 <p>IS43R16320D-6BI-TR ISSI (Integrated Silicon Solution, Inc.) IC DRAM 512M PARALLEL 60TFBGA</p>	 <p>IS43R16320D-6BLI ISSI (Integrated Silicon Solution, Inc.) IC SDRAM 512MBIT 167MHZ 60BGA</p>

heiße Teile

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|-----------------------|--------------------------|------------------------|-----------------------|--------------------------|
| ⚙ IS43DR16320B25DBLI | ↔ IS43DR16320C-25DBLI-TR | ⇒ IS43DR16640A-3DBI | D IS43DR16640A-3DBL | ⇒ IS43DR16640A-3DBLI |
| ⊣ IS43DR16640B-25DBLI | ⚙ IS43DR16640B-25DBLI-TR | D IS43DR16640B-3DBI | ⇒ IS43DR16640B-3DBL | ⇒ IS43DR16640C-25DBLI-TR |
| ⚙ IS43DR81280A-25DBLI | ⊣ IS43DR81280A-3DBL | ⚙ IS43DR81280A-3DBLI | ↔ IS43DR82560B-25EBLI | ⇒ IS43DR82560B-25EBLI |
| D IS43DR86400B-3DBL | ⚙ IS43LR32160B-6BL | ⊣ IS43R16160B-5TLI | ⚙ IS43R16160B-6BI | ⇒ IS43R16160B-6TL |
| ⇒ IS43R16160D-5BL | ↔ IS43R16160D-5TL-TR | ⚙ IS43R16160D-6BI | ⊣ IS43R16320B-6TL | ⇒ IS43R16320D-5TLI |
| ↔ IS43R16320D-6BI | ⇒ IS43R16320D-6BI-TR | D IS43R16320D-6BI-TR | ⚙ IS43R16800CC-6TL | ⊣ IS43R16800E-5TL |
| ⚙ IS43R32800B-5BI | D IS43R32800B-5BL | ⇒ IS43R86400D-5BLI | ↔ IS43TR16128A-15HBL | ⇒ IS43TR16256A-125KBLI |
| ⊣ IS43TR16640A-15GBL | ⚙ IS43TR16640A-15GBLI | ↔ IS43TR16640A-15HBLI | ⇒ IS43TR81280A-15GBL | ⇒ IS43TR81280A-15GBLI |
| ⚙ IS43TR81280A-15HBL | ⊣ IS43TR81280A-15HBLI | ⚙ IS43TR85120A-125KBLI | D IS45S16100C1-7BLA1 | ⇒ IS45S16100C1-7BLA1-T |
| ↔ IS45S16100E-7TLA1 | ⚙ IS45S16160C-7TLA1 | ⊣ IS45S16160D-7BLA1 | ⚙ IS45S16160D-7BLA2 | ⇒ IS45S16320B-7CTNA1 |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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